





Texas INSTRUMENTS

SNx4HCT245 Octal Bus Transceivers With 3-State Outputs

1 Features

- Operating voltage range of 4.5 V to 5.5 V
- High-Current 3-state outputs drive bus lines ٠ directly or up to 15-LSTTL loads
- Low power consumption, 80-µA maximum I_{CC}
- Typical t_{pd} = 14 ns •
- ±6-mA output drive at 5 V •
- Low input current of 1 µA maximum
- Inputs are TTL-voltage compatible

2 Applications

- Factory Automation and Control •
- Grid Infrastructure
- **Electronic Point of Sale**
- Multi-Function Printers
- Motor Drives •
- Storage
- **Telecom Infrastructure**

3 Description

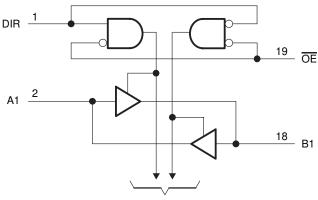
The SNx4HCT245 bus transceivers octal are designed for asynchronous two-way communication between data buses. The controlfunction implementation minimizes external timing requirements.

The SNx4HCT245 devices allow data transmission from the A bus to the B bus or from the B bus to the A bus, depending upon the logic level at the directioncontrol (DIR) input. The output-enable (\overline{OE}) input can be used to disable the device so that the buses are effectively isolated.

Device information									
PACKAGE ⁽¹⁾	BODY SIZE (NOM)								
J (CDIP, 20)	24.20 mm × 6.92 mm								
FK (LCCC, 20)	8.89 mm × 8.89 mm								
W (CFP, 20)	13.09 mm × 6.92 mm								
DW (SOIC, 20)	12.80 mm × 7.50 mm								
N (PDIP, 20)	24.33 mm × 6.35 mm								
NS (SO, 20)	12.60 mm × 5.30 mm								
PW (TSSOP, 20)	6.50 mm × 4.40 mm								
DB (SSOP, 20)	7.80 mm × 7.20 mm								
DGS (VSSOP, 20)	5.10 mm × 3.00 mm								
	PACKAGE ⁽¹⁾ J (CDIP, 20) FK (LCCC, 20) W (CFP, 20) DW (SOIC, 20) N (PDIP, 20) NS (SO, 20) PW (TSSOP, 20) DB (SSOP, 20)								

Device Information

For all available packages, see the orderable addendum at (1) the end of the data sheet.



To Seven Other Channels Copyright © 2016, Texas Instruments Incorporated

Logic Diagram (Positive Logic)





Table of Contents

1 Features1	
2 Applications1	
3 Description1	
4 Revision History	
5 Pin Configuration and Functions	
6 Specifications	
6.1 Absolute Maximum Ratings4	
6.2 ESD Ratings	
6.3 Recommended Operating Conditions4	
6.4 Thermal Information5	12
6.5 Electrical Characteristics5	
6.6 Switching Characteristics: C _L = 50 pF6	i
6.7 Switching Characteristics: $C_L = 150 \text{ pF}$	
6.8 Operating Characteristics	
6.9 Typical Characteristics7	·
7 Parameter Measurement Information	1
8 Detailed Description	1
8.1 Overview	13
8.2 Functional Block Diagram9	

	8.3 Feature Description	9
	8.4 Device Functional Modes	
9	Application and Implementation	
	9.1 Application Information	10
	9.2 Typical Application	10
1(0 Power Supply Recommendations	.12
1	1 Layout	12
	11.1 Layout Guidelines	
	11.2 Layout Example	
12	2 Device and Documentation Support	.13
	12.1 Documentation Support	
	12.2 Related Links	13
	12.3 Receiving Notification of Documentation Updates.	.13
	12.4 Support Resources	
	12.5 Trademarks	
	12.6 Electrostatic Discharge Caution	
	12.7 Glossary	
1:	3 Mechanical, Packaging, and Orderable	
	Information	13

4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

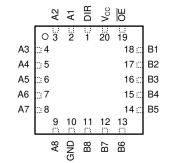
С	hanges from Revision G (September 2022) to Revision H (December 2022)	Page
•	Added DGS package information	1
	Added DGS package values in the Thermal Information table	
С	hanges from Revision F (August 2016) to Revision G (September 2022)	Page
•	Updated the numbering format for tables, figures and cross-references throughout the document	1
С	hanges from Revision E (August 2003) to Revision F (August 2016)	Page
•	Deleted Ordering Information, see POA at the end of the datasheet	1
•	Added ESD Ratings table, Feature Description section, Device Functional Modes, Application and	
	Implementation section, Power Supply Recommendations section, Layout section, Device and	
	Documentation Support section, and Mechanical, Packaging, and Orderable Information section	1
•	Updated values in the Thermal Information table	



5 Pin Configuration and Functions

DIR 🗖	1	20	
A1 🗖	2	19	
A2 🗖	3	18	🗖 B1
A3 🗔	4	17	🗖 В2
A4 🗖	5	16	🗖 ВЗ
A5 🗖	6	15	🗖 В4
A6 🗖	7	14	🗖 B5
A7 🗖	8	13	 B6
A8 🗖	9	12	B7
GND 🗖	10	11	B 8

GND 10 11 B8 J, W, DB, DW, N, NS, PW or DGS Packages 20-Pin CDIP, CFP, SSOP, SOIC, PDIP, SO, TSSOP or VSSOP Top View



FK Package 20-Pin LCCC Top View

Pin Functions

PIN		TYPE ⁽¹⁾	DESCRIPTION
NO. NAME			DESCRIPTION
1	DIR	I	Direction select. High = A to B, Low = B to A
2	A1	I/O	Channel 1 port A
3	A2	I/O	Channel 2 port A
4	A3	I/O	Channel 3 port A
5	A4	I/O	Channel 4 port A
6	A5	I/O	Channel 5 port A
7	A6	I/O	Channel 6 port A
8	A7	I/O	Channel 7 port A
9	A8	I/O	Channel 8 port A
10	GND	_	Ground
11	B8	O/I	Channel 8 port B
12	B7	O/I	Channel 7 port B
13	B6	O/I	Channel 6 port B
14	B5	O/I	Channel 5 port B
15	B4	O/I	Channel 4 port B
16	B3	O/I	Channel 3 port B
17	B2	O/I	Channel 2 port B
18	B1	O/I	Channel 1 port B
19	ŌĒ	I	Output enable, active low. High = all ports in high impedance mode, Low = all ports active
20	V _{CC}	—	Power supply

(1) Signal Types: I = Input, O = Output, I/O = Input or Output



6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

			MIN	MAX	UNIT
V _{CC}	Supply voltage		-0.5	7	V
I _{IK}	Input clamp current ⁽²⁾	$V_{I} < 0 \text{ or } V_{I} > V_{CC}$		±20	mA
I _{ок}	Output clamp current ⁽²⁾	$V_{\rm O}$ < 0 or $V_{\rm O}$ > $V_{\rm CC}$		±20	mA
lo	Continuous output current	$V_{O} = 0$ to V_{CC}		±35	mA
	Continuous current through V_{CC} or GND	· · · · ·		±70	mA
TJ	Operating virtual junction temperature			150	°C
T _{stg}	Storage temperature		-65	150	°C

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

6.2 ESD Ratings

			VALUE	UNIT
		Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	±1500	
V _(ESD)	Electrostatic discharge	Charged-device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾	±2000	V

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

			MIN	NOM	MAX	UNIT
V _{CC}	Supply voltage		4.5	5	5.5	V
V _{IH}	High-level input voltage	V_{CC} = 4.5 V to 5.5 V	2			V
V _{IL}	Low-level input voltage	V_{CC} = 4.5 V to 5.5 V			0.8	V
VI	Input voltage		0		V _{CC}	V
Vo	Output voltage		0		V _{CC}	V
Δt/Δv	Input transition rise and fall time			·	500	ns
т	Operating free-air temperature	SN54HCT245	-55		125	°C
IA		SN74HCT245	-40		85	C

 All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. See the TI application report, Implications of Slow or Floating CMOS Inputs (SCBA004).



6.4 Thermal Information

		SNx4HCT245									
THERMAL METRIC ⁽¹⁾		J (CDIP)	W (CFP)	FK (LCCC)	DB (SSOP)	DW (SOIC)	N (PDIP)	NS (SO)	PW (TSS OP)	DGS (VSS OP)	UNIT
		20 PINS	20 PINS	20 PINS	20 PINS	20 PINS	20 PINS	20 PINS	20 PINS	20 PINS	
R _{0JA}	Junction-to-ambient thermal resistance	_	—	—	84.6	70.4	43.4	68.9	94.9	118.4	°C/W
R _{0JC(top)}	Junction-to-case (top) thermal resistance	38.7	60.8	37.1	44.3	36.5	29.5	34.7	30.2	57.7	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	49.8	100.4	36.1	40.2	38.1	24.3	36.4	45.7	73.1	°C/W
Ψ_{JT}	Junction-to-top characterization parameter	_	_	_	11.1	11.3	15	11.6	1.5	5.7	°C/W
Ψ_{JB}	Junction-to-board characterization parameter	_	_	_	39.7	37.7	24.2	36	45.1	72.7	°C/W
R _{0JC(bot)}	Junction-to-case (bottom) thermal resistance	11.5	8.5	4.3	_	_	_	_	_	_	°C/W

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

6.5 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

	PARAMETER	TEST C	ONDITI	ONS	V _{cc}	MIN	TYP	MAX	UNIT	
				I _{OH} =	T _A = 25°C		4.4	4.499		
				-20	SN54HCT245		4.4			
V _{OH}	High-Level Output Voltage		$V_{I} = V_{IH} \text{ or } V_{IL}$	μA	SN74HCT245	4.5 V	4.4			V
V OH					T _A = 25°C	4.5 V	3.98	4.3		v
				I _{ОН} = –6 mA	SN54HCT245		3.7			
					SN74HCT245		3.84			
					T _A = 25°C			0.001	0.1	
				Ι _{ΟL} = 20 μΑ	SN54HCT245				0.1	
V _{OL}	Low-Level Output Voltage		$V_{I} = V_{IH}$ or V_{IL}		SN74HCT245	4.5 V			0.1	v
VOL					T _A = 25°C	4.0 V		0.17	0.26	v
				6 MA	SN54HCT245	-			0.4	-
					SN74HCT245				0.33	
		DID		T _A = 25	5°C			±0.1	±100	
li –	Input Current DIR OF	DIR or OE	$V_{I} = V_{CC} \text{ or } 0$	SN54⊢	ICT245	5.5 V			±1000	nA
				SN74⊢	SN74HCT245				±1000	
				T _A = 28	5°C			±0.01	±0.5	
I _{OZ}	Off-State Output Current	A or B	$V_{O} = V_{CC} \text{ or } 0$	SN54H	ICT245	5.5 V			±10	μA
					ICT245				±5	
					T _A = 25°C				8	
I _{CC}	Supply Current	Supply Current $V_{I} = V_{CC}$ or 0	$V_{I} = V_{CC} \text{ or } 0$	I _O = 0	SN54HCT245	5.5 V			160	μA
					SN74HCT245				80	
	N _{CC} ⁽¹⁾ Supply-Current Change		One input at 0.5 V	T _A = 28	T _A = 25°C			1.4	2.4	
ΔI_{CC} ⁽¹⁾			or 2.4 V, Other inputs at 0 or	SN54HCT245 SN74HCT245		5.5 V			3	
00			VCC						2.9	



over recommended operating free-air temperature range (unless otherwise noted)

	PARAMETER		TEST CONDITIONS	V _{cc}	MIN	TYP	MAX	UNIT
			$T_A = 25^{\circ}C$	4.5 V		3	10	
C _i ⁽²⁾ Input 0	Input Capacitance	DIR or OE	SN54HCT245	to			10	pF
			SN74HCT245	5.5 V			10	1

(1) This is the increase in supply current for each input that is at one of the specified TTL voltage levels, rather than 0 V or V_{CC} . (2) Parameter C_i does not apply to transceiver I/O ports.

6.6 Switching Characteristics: C_L = 50 pF

over recommended operating free-air temperature range, C_L = 50 pF (unless otherwise noted) (see Figure 7-1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{cc}	TEST CONDITIONS	MIN	ТҮР	МАХ	UNIT			
				T _A = 25°C		16	22				
			4.5 V	SN54HCT245			33				
	A or B	B or A		SN74HCT245			28	20			
t _{pd}	AUD	BUIA		T _A = 25°C		14	20	ns			
			5.5 V	SN54HCT245			30				
				SN74HCT245			25				
				T _A = 25°C		25	46				
			4.5 V	SN54HCT245			69				
	ŌĒ	A or B		SN74HCT245			58	ns			
t _{en}	UL			T _A = 25°C		22	41	115			
			5.5 V	SN54HCT245			62				
				SN74HCT245			52				
				T _A = 25°C		26	40				
			4.5 V	SN54HCT245			60				
+	ŌĒ	A or B		SN74HCT245			50	nc			
t _{dis}	UE	AUB		T _A = 25°C		23	36	ns			
						5.5 V	SN54HCT245			54	
				SN74HCT245			45				
				T _A = 25°C		9	12				
			4.5 V	SN54HCT245			18				
	A or B	A or B		SN74HCT245			15	ns			
^t t			T _A = 25°C		8	11	115				
			5.5 V	SN54HCT245			16				
				SN74HCT245			14				



17

14

42

63

53

38

57

48

ns

6.7 Switching Characteristics: C_L = 150 pF

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{cc}	TEST CONDITIONS	MIN	ТҮР	МАХ	UNIT
				T _A = 25°C		20	30	
			4.5 V	SN54HCT245			45	
	A	D an A		SN74HCT245			38	
t _{pd}	A or B	B or A		T _A = 25°C		18	27	ns
			5.5 V	SN54HCT245			41	
				SN74HCT245			34	
				T _A = 25°C		36	59	
			4.5 V	SN54HCT245			89	
t _{en} OE			SN74HCT245			74		
	ÛE	A or B		T _A = 25°C		30	53	ns
			5.5 V	SN54HCT245			80	
				SN74HCT245			67	

4.5 V

5.5 V

A or B

T_A = 25°C

T_A = 25°C

SN54HCT245

SN74HCT245

SN54HCT245

SN74HCT245

over recommended operating free-air temperature range, $C_1 = 150 \text{ pF}$ (unless otherwise noted) (see Figure 7-1)

6.8 Operating Characteristics

T_A = 25°C

tt

	PARAMETER	TEST CONDITIONS	TYP	UNIT
C _{pd}	Power dissipation capacitance per transceiver	No load	40	pF

6.9 Typical Characteristics

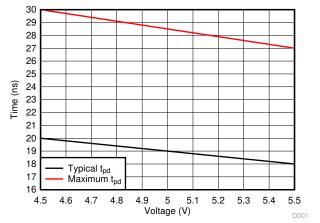
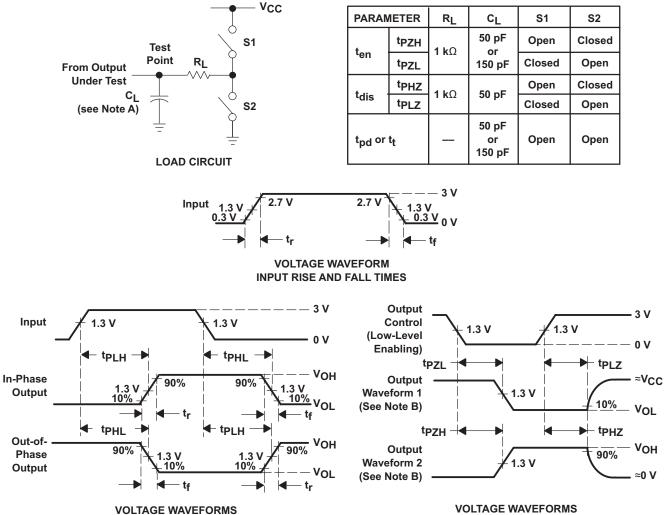
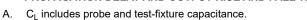


Figure 6-1. Propagation Delay Over Operating Voltage Range, T_A = 25°C

7 Parameter Measurement Information



PROPAGATION DELAY AND OUTPUT RISE AND FALL TIMES





- Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Β. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- Phase relationships between waveforms were chosen arbitrarily. All input pulses are supplied by generators having the following C. characteristics: PRR \leq 1 MHz, Z_O = 50 Ω , t_r = 6 ns, t_f = 6 ns.
- The outputs are measured one at a time with one input transition per measurement. D.
- Ε. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- F. t_{PZL} and t_{PZH} are the same as t_{en}.
- G. t_{PLH} and t_{PHL} are the same as t_{pd}.

Figure 7-1. Load Circuit and Voltage Waveforms

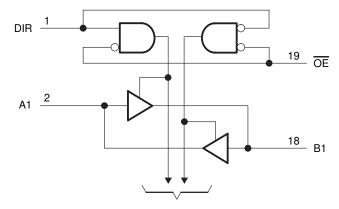


8 Detailed Description

8.1 Overview

The SNx4HCT245 is a bidirectional buffer with direction control and active low output enable. This device is commonly used in logic systems for isolation and increasing drive strength.

8.2 Functional Block Diagram



To Seven Other Channels Copyright © 2016, Texas Instruments Incorporated

Figure 8-1. Logic Diagram (Positive Logic)

8.3 Feature Description

Voltage operating range from 4.5 V to 5.5 V is forgiving of 5-V power supply rail accuracy. Outputs can operate up to 15 LSTTL loads. This device has balanced propagation delay, typically 14 ns, and balanced output drive of ± 6 mA at 5 V. It has low power consumption of only 80-µA maximum static supply current. The center V_{CC} and GND pin configurations minimize high-speed switching noise. Inputs are TTL-voltage compatible.

8.4 Device Functional Modes

This device is a standard '245 logic function. It has an active low output enable, a direction pin, and eight communication channels.

	able 8-1. Funct	ion lable
INPU	TS ⁽¹⁾	OPERATION
ŌĒ	DIR	OFERATION
L	L	B data to A bus
L	Н	A data to B bus
Н	Х	Isolation

Table 8-1. Function Table

(1) H = High Voltage Level, L = Low Voltage Level, X = Don't Care



9 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

9.1 Application Information

The SNx4HCT245 is a versatile device with many available applications. The application chosen as an example here is connecting a master and slave device through a ribbon cable. This configuration is common due to losses in this type of cable.

9.2 Typical Application

Logic transceivers are commonly seen in back plane and ribbon cable applications where a signal direct from an FPGA or MCU would be too weak to reach the distant end. The transceiver acts as an amplifier to get the signal across the line, and since it is bidirectional, data can be sent from master to slave or slave to master. The additional buffer on the direction line is necessary to ensure the direction signal can always reach the distant end.

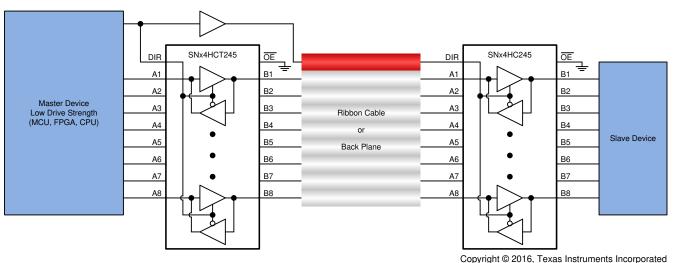


Figure 9-1. Typical application for SNx4HC245

9.2.1 Design Requirements

This device uses CMOS technology and has balanced output drive. Care must be taken to avoid bus contention because it can drive currents that would exceed maximum limits. Outputs can be combined to produce higher drive, but the high drive also creates faster edges into light loads, so routing and load conditions must be considered to prevent ringing.

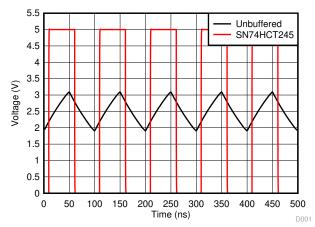
9.2.2 Detailed Design Procedure

- 1. Recommended Input Conditions
 - Rise time and fall time specs: See ($\Delta t/\Delta V$) in the *Recommended Operating Conditions*.
 - Specified high and low levels: See (VIH and VIL) in the Recommended Operating Conditions.
- 2. Recommended Output Conditions
 - Load currents should not exceed 35 mA per output and 70 mA total for the part.
 - Outputs should not be pulled above V_{CC}.



9.2.3 Application Curve

It is common to see significant losses in ribbon cables and back planes. The plot shown in Figure 9-2 is a simplified simulation of a ribbon cable from a 5-V, 10-MHz low drive strength source. It shows the difference between an input signal from a weak driver like an MCU or FPGA compared to a strong driver like the SN74HCT245 when measured at the distant end of the cable. By adding a high-current drive transceiver before the cable, the signal strength can be significantly improved, and subsequently the cable can be longer.



Unbuffered line is directly connected to low current source, SN74HCT245 line is buffered through the transceiver. Both signals are measured at the distant end of the ribbon cable.

Figure 9-2. Simulated Outputs From Ribbon Cable With a 5-V, 10-MHz Source



10 Power Supply Recommendations

The power supply can be any voltage between the MIN and MAX supply voltage rating located in the *Recommended Operating Conditions*. Each V_{CC} pin must have a good bypass capacitor to prevent power disturbance. For devices with a single supply, 0.1 μ F is recommended; if there are multiple VCC pins, then 0.01 μ F or 0.022 μ F is recommended for each power pin. It is acceptable to parallel multiple bypass capacitors to reject different frequencies of noise. A 0.1 μ F and a 1 μ F are commonly used in parallel. The bypass capacitor should be installed as close to the power pin as possible for best results.

11 Layout

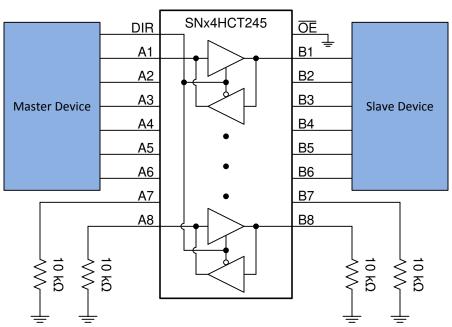
11.1 Layout Guidelines

When using multiple-bit logic devices, inputs should never float.

In many cases, functions or parts of functions of digital logic devices are unused, for example, when only six channels of an eight channel transceiver are used. Such input pins should not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that should be applied to any particular unused input depends on the function of the device. Generally they are tied to GND or V_{CC} , whichever makes more sense or is more convenient.

The output enable pin disables the output section of the part when asserted. This does not disable the input section of the IOs, so they cannot float when disabled.

Figure 11-1 shows the proper method to terminate unused channels using a large resistance (in this example, $10-k\Omega$ resistors). This avoids overloading the outputs , and maintains a valid voltage on the inputs. Note that it is also valid to tie both sides of an unused transceiver directly to ground or V_{CC}; however, the two sides must never be tied to different states directly.



11.2 Layout Example

Figure 11-1. Proper Termination of OE Pin And Unused Channels 7 and 8



12 Device and Documentation Support

12.1 Documentation Support

12.1.1 Related Documentation

For related documentation see the following:

Implications of Slow or Floating CMOS Inputs (SCBA004)

12.2 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

		Table 12-1. R	kelated Links		
PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY
SN54HCT245	Click here	Click here	Click here	Click here	Click here
SN74HCT245	Click here	Click here	Click here	Click here	Click here

Table 12-1. Related Links

12.3 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

12.4 Support Resources

TI E2E[™] support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

12.5 Trademarks

TI E2E[™] is a trademark of Texas Instruments.

All trademarks are the property of their respective owners.

12.6 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

12.7 Glossary

TI Glossary This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
5962-8550601VRA	Active	Production	CDIP (J) 20	20 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-8550601VR A SNV54HCT245J
5962-8550601VRA.A	Active	Production	CDIP (J) 20	20 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-8550601VR A SNV54HCT245J
5962-8550601VSA	Active	Production	CFP (W) 20	25 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-8550601VS A SNV54HCT245W
5962-8550601VSA.A	Active	Production	CFP (W) 20	25 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-8550601VS A SNV54HCT245W
85506012A	Active	Production	LCCC (FK) 20	55 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	85506012A SNJ54HCT 245FK
8550601RA	Active	Production	CDIP (J) 20	20 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	8550601RA SNJ54HCT245J
JM38510/65553BRA	Active	Production	CDIP (J) 20	20 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	JM38510/ 65553BRA
JM38510/65553BRA.A	Active	Production	CDIP (J) 20	20 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	JM38510/ 65553BRA
JM38510/65553BSA	Active	Production	CFP (W) 20	25 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	JM38510/ 65553BSA
JM38510/65553BSA.A	Active	Production	CFP (W) 20	25 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	JM38510/ 65553BSA
M38510/65553BRA	Active	Production	CDIP (J) 20	20 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	JM38510/ 65553BRA
M38510/65553BSA	Active	Production	CFP (W) 20	25 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	JM38510/ 65553BSA
SN54HCT245J	Active	Production	CDIP (J) 20	20 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	SN54HCT245J
SN54HCT245J.A	Active	Production	CDIP (J) 20	20 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	SN54HCT245J
SN74HCT245DBR	Active	Production	SSOP (DB) 20	2000 LARGE T&R	Yes	NIPDAU NIPDAU	Level-1-260C-UNLIM	-40 to 85	HT245
SN74HCT245DBR.A	Active	Production	SSOP (DB) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HT245



20-Aug-2025

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
SN74HCT245DBRG4	Active	Production	SSOP (DB) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HT245
SN74HCT245DGSR	Active	Production	VSSOP (DGS) 20	5000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HT245
SN74HCT245DGSR.A	Active	Production	VSSOP (DGS) 20	5000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HT245
SN74HCT245DW	Obsolete	Production	SOIC (DW) 20	-	-	Call TI	Call TI	-40 to 85	HCT245
SN74HCT245DWR	Active	Production	SOIC (DW) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HCT245
SN74HCT245DWR.A	Active	Production	SOIC (DW) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HCT245
SN74HCT245DWRE4	Active	Production	SOIC (DW) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HCT245
SN74HCT245DWRG4	Active	Production	SOIC (DW) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HCT245
SN74HCT245N	Active	Production	PDIP (N) 20	20 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 85	SN74HCT245N
SN74HCT245N.A	Active	Production	PDIP (N) 20	20 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 85	SN74HCT245N
SN74HCT245NE4	Active	Production	PDIP (N) 20	20 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 85	SN74HCT245N
SN74HCT245NSR	Active	Production	SOP (NS) 20	2000 LARGE T&R	Yes	NIPDAU NIPDAU	Level-1-260C-UNLIM	-40 to 85	HCT245
SN74HCT245NSR.A	Active	Production	SOP (NS) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HCT245
SN74HCT245PW	Obsolete	Production	TSSOP (PW) 20	-	-	Call TI	Call TI	-40 to 85	HT245
SN74HCT245PWR	Active	Production	TSSOP (PW) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HT245
SN74HCT245PWR.A	Active	Production	TSSOP (PW) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HT245
SN74HCT245PWR.B	Active	Production	TSSOP (PW) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HT245
SN74HCT245PWRE4	Active	Production	TSSOP (PW) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HT245
SN74HCT245PWRG4	Active	Production	TSSOP (PW) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HT245
SN74HCT245PWRG4.A	Active	Production	TSSOP (PW) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HT245
SN74HCT245PWRG4.B	Active	Production	TSSOP (PW) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HT245
SN74HCT245PWT	Obsolete	Production	TSSOP (PW) 20	-	-	Call TI	Call TI	-40 to 85	HT245
SNJ54HCT245FK	Active	Production	LCCC (FK) 20	55 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	85506012A SNJ54HCT 245FK
SNJ54HCT245FK.A	Active	Production	LCCC (FK) 20	55 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	85506012A SNJ54HCT 245FK
SNJ54HCT245J	Active	Production	CDIP (J) 20	20 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	8550601RA SNJ54HCT245J
SNJ54HCT245J.A	Active	Production	CDIP (J) 20	20 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	8550601RA SNJ54HCT245J



20-Aug-2025

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
						(4)	(5)		
SNJ54HCT245W	Active	Production	CFP (W) 20	25 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	SNJ54HCT245W
SNJ54HCT245W.A	Active	Production	CFP (W) 20	25 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	SNJ54HCT245W

⁽¹⁾ Status: For more details on status, see our product life cycle.

⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(⁵⁾ MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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OTHER QUALIFIED VERSIONS OF SN54HCT245, SN54HCT245-SP, SN74HCT245 :

• Catalog : SN74HCT245, SN54HCT245

• Military : SN54HCT245



20-Aug-2025

• Space : SN54HCT245-SP

NOTE: Qualified Version Definitions:

• Catalog - TI's standard catalog product

- Military QML certified for Military and Defense Applications
- Space Radiation tolerant, ceramic packaging and qualified for use in Space-based application



Texas

STRUMENTS

TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74HCT245DBR	SSOP	DB	20	2000	330.0	16.4	8.2	7.5	2.5	12.0	16.0	Q1
SN74HCT245DGSR	VSSOP	DGS	20	5000	330.0	16.4	5.4	5.4	1.45	8.0	16.0	Q1
SN74HCT245DWR	SOIC	DW	20	2000	330.0	24.4	10.9	13.3	2.7	12.0	24.0	Q1
SN74HCT245NSR	SOP	NS	20	2000	330.0	24.4	8.4	13.0	2.5	12.0	24.0	Q1
SN74HCT245PWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.0	1.4	8.0	16.0	Q1
SN74HCT245PWRG4	TSSOP	PW	20	2000	330.0	16.4	6.95	7.0	1.4	8.0	16.0	Q1



www.ti.com

PACKAGE MATERIALS INFORMATION

24-Jul-2025

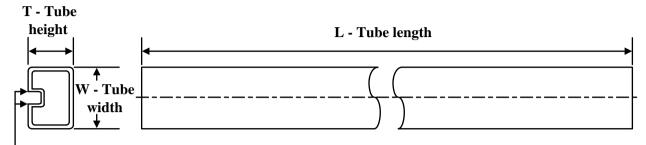


All differisions are norminal							r.
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74HCT245DBR	SSOP	DB	20	2000	353.0	353.0	32.0
SN74HCT245DGSR	VSSOP	DGS	20	5000	353.0	353.0	32.0
SN74HCT245DWR	SOIC	DW	20	2000	356.0	356.0	45.0
SN74HCT245NSR	SOP	NS	20	2000	356.0	356.0	45.0
SN74HCT245PWR	TSSOP	PW	20	2000	353.0	353.0	32.0
SN74HCT245PWRG4	TSSOP	PW	20	2000	353.0	353.0	32.0

TEXAS INSTRUMENTS

www.ti.com

TUBE



- B - Alignment groove width

*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	Τ (μm)	B (mm)
5962-8550601VSA	W	CFP	20	25	506.98	26.16	6220	NA
5962-8550601VSA.A	W	CFP	20	25	506.98	26.16	6220	NA
85506012A	FK	LCCC	20	55	506.98	12.06	2030	NA
JM38510/65553BSA	W	CFP	20	25	506.98	26.16	6220	NA
JM38510/65553BSA.A	W	CFP	20	25	506.98	26.16	6220	NA
M38510/65553BSA	W	CFP	20	25	506.98	26.16	6220	NA
SN74HCT245N	N	PDIP	20	20	506	13.97	11230	4.32
SN74HCT245N.A	N	PDIP	20	20	506	13.97	11230	4.32
SN74HCT245NE4	N	PDIP	20	20	506	13.97	11230	4.32
SNJ54HCT245FK	FK	LCCC	20	55	506.98	12.06	2030	NA
SNJ54HCT245FK.A	FK	LCCC	20	55	506.98	12.06	2030	NA
SNJ54HCT245W	W	CFP	20	25	506.98	26.16	6220	NA
SNJ54HCT245W.A	W	CFP	20	25	506.98	26.16	6220	NA

J (R-GDIP-T**) 14 LEADS SHOWN

CERAMIC DUAL IN-LINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

FK 20

8.89 x 8.89, 1.27 mm pitch

GENERIC PACKAGE VIEW

LCCC - 2.03 mm max height

LEADLESS CERAMIC CHIP CARRIER

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.





N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- \triangle The 20 pin end lead shoulder width is a vendor option, either half or full width.



DW0020A



PACKAGE OUTLINE

SOIC - 2.65 mm max height

SOIC



NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



DW0020A

EXAMPLE BOARD LAYOUT

SOIC - 2.65 mm max height

SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



DW0020A

EXAMPLE STENCIL DESIGN

SOIC - 2.65 mm max height

SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



W (R-GDFP-F20)

CERAMIC DUAL FLATPACK



- NOTES: A. All linear dimensions are in inches (millimeters).
 - This drawing is subject to change without notice. В.
 - C. This package can be hermetically sealed with a ceramic lid using glass frit.
 D. Index point is provided on cap for terminal identification only.
 E. Falls within Mil-Std 1835 GDFP2-F20



PW0020A



PACKAGE OUTLINE

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



PW0020A

EXAMPLE BOARD LAYOUT

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



PW0020A

EXAMPLE STENCIL DESIGN

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



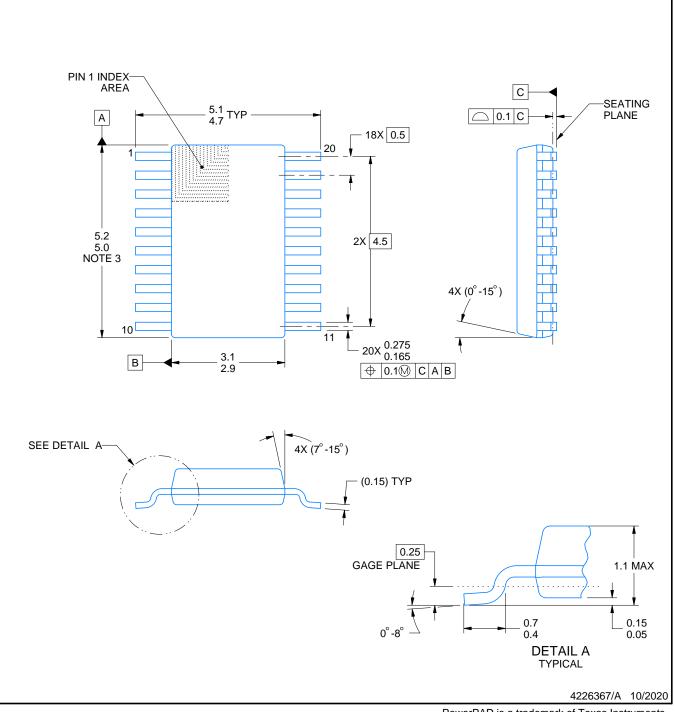
DGS0020A



PACKAGE OUTLINE

VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



NOTES:

PowerPAD is a trademark of Texas Instruments.

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. No JEDEC registration as of September 2020.
- 5. Features may differ or may not be present.

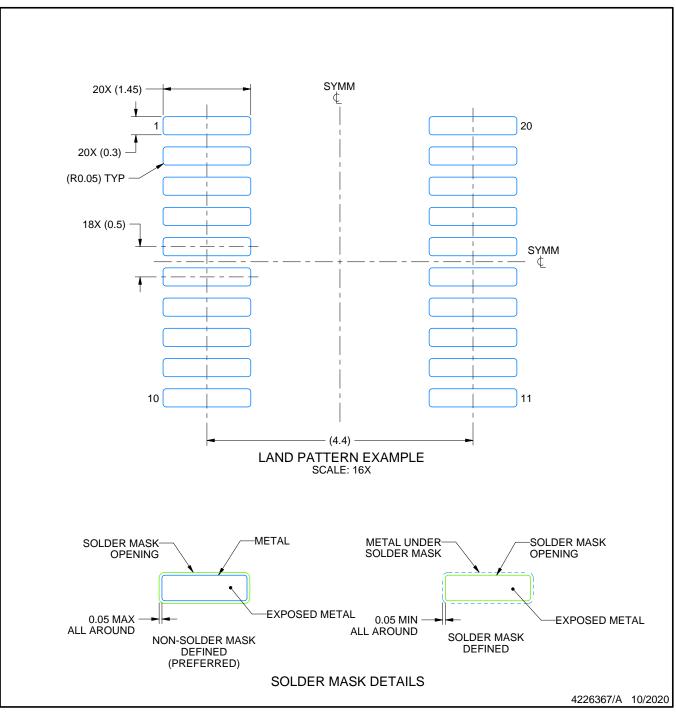


DGS0020A

EXAMPLE BOARD LAYOUT

VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
- 8. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature numbers SLMA002 (www.ti.com/lit/slma002) and SLMA004 (www.ti.com/lit/slma004).
- 9. Size of metal pad may vary due to creepage requirement.
- 10. Vias are optional depending on application, refer to device data sheet. It is recommended that vias under paste be filled, plugged or tented.

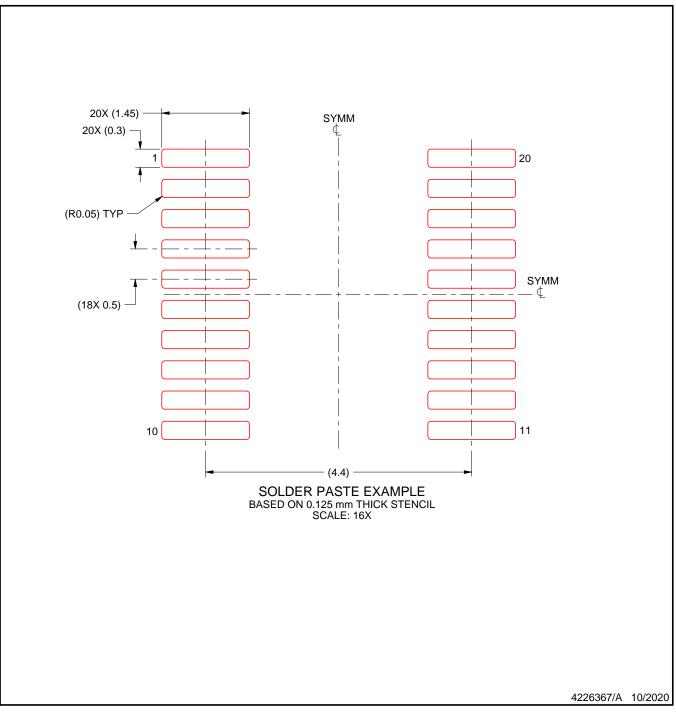


DGS0020A

EXAMPLE STENCIL DESIGN

VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

- 11. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 12. Board assembly site may have different recommendations for stencil design.



DB0020A



PACKAGE OUTLINE

SSOP - 2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-150.



DB0020A

EXAMPLE BOARD LAYOUT

SSOP - 2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



DB0020A

EXAMPLE STENCIL DESIGN

SSOP - 2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



MECHANICAL DATA

PLASTIC SMALL-OUTLINE PACKAGE

0,51 0,35 ⊕0,25⊛ 1,27 8 14 0,15 NOM 5,60 8,20 5,00 7,40 \bigcirc Gage Plane ₽ 0,25 7 1 1,05 0,55 0-10 Δ 0,15 0,05 Seating Plane — 2,00 MAX 0,10PINS ** 14 16 20 24 DIM 10,50 10,50 12,90 15,30 A MAX A MIN 9,90 9,90 12,30 14,70 4040062/C 03/03

NOTES: A. All linear dimensions are in millimeters.

NS (R-PDSO-G**)

14-PINS SHOWN

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



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